HD14519B

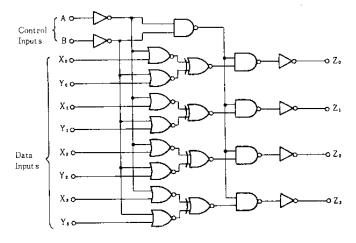
4-bit AND/OR Selector or Quadruple 2-Channel Data Selector or Quadruple Exclusive-NOR Gate

The HD14519B finds primary use where low power dissipation and/or high noise immunity is desired. This device exemplifies the design versatility of CMOS logic structure. This part provides three functions in one package; a 4-bit AND/OR Selector, a Quad 2-channel Data Selector, or a Quad Exclusive NOR Gate.

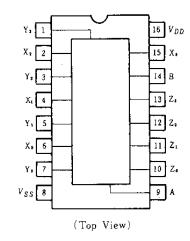
■ FEATURES

- Quiescent Current = 5nA/pkg typ. @5V
- Noise Immunity = 45% of V_{DD} typ.
- Supply Voltage Range = 3 to 18V
- Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range
- Pin-for-Pin Compatible with HD14519B.

■LOGIC DIAGRAM



■ PIN ARRANGEMENT

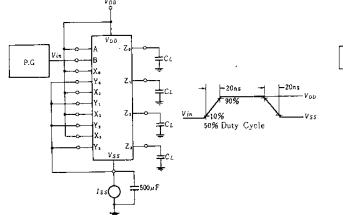


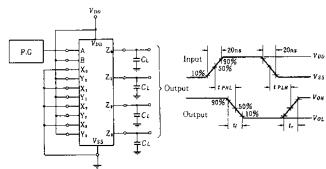
TRUTH TABLE

Contro	l Inputs	Outputs		
A	В	Zn		
0	0	0		
0	1	Yn		
1	0	Xn		
1	1	Xn⊕Yn		

■ POWER DISSIPATION TEST CIRCUIT AND WAVEFORM

SWITCHING TIME TEST CIRCUIT





■ ELECTRICAL CHARACTERISTICS

Characteristic S	Symbol	Test Conditions		-40°C		25°C			85°C		**	
Sharacteristic Symbo		$V_{DD}(V)$ lest Conditions		min	max	min	typ	max	min	max	Unit	
Output Voltage		5.0			0.05	_	0	0.05	_	0.05	v	
	Vol	10	$V_{in}=V_{DD}$ or $oldsymbol{0}$	_	0.05	-	0	0.05	_	0.05		
		15		_	0.05	-	0	0.05	_	0.05		
		5.0		4.95	_	4.95	5.0	_	4.95	-	v	
	V _{OH}	10	$V_{in}\!=\!0$ or V_{DD}	9.95	-	9.95	10	_	9.95	_		
		15		14.95	-	14.95	15	_	14.95	_		
-		5.0	$V_{out} = 4.5 \text{ or } 0.5V$	$V_{out} = 4.5 \text{ or } 0.5V$ - 1.5 - 2.25		1.5	_	1.5				
	V_{IL}	10	$V_{out}=9.0$ or $1.0\mathrm{V}$		3.0	_	4.50	3.0	-	3.0	V	
Input Voltage		15	Vout = 13.5 or 1.5V - 4.0 - 6.75 4.6		4.0		4.0					
		5.0	$V_{\text{out}} = 0.5 \text{ or } 4.5\text{V}$	3.5	_	3.5	2.75	_	3.5	-	v	
	V_{IH}	10	$V_{out} = 1.0 \text{ or } 9.0 \text{V}$	7.0		7.0	5.50		7.0	_		
		15	$V_{out} = 1.5 \text{ or } 13.5\text{V}$	11.0	_	11.0	8.25	_	11.0	_		
Output Drive Current		5.0	$V_{OH}=2.5V$	-1.0	_	-0.8	-1.7	_	-0.6		mA	
	J	5.0	$V_{OH} = 4.6 \text{V}$	-0.2		-0.16	-0.36	_	-0.12	_		
	Іон	10	$V_{OH}=9.5V$	-0.5	_	-0.4	-0.9		-0.3	_		
		15	$V_{OH} = 13.5 \text{V}$	-1.4		-1.2	-3.5	_	-1.0			
		5.0	$V_{OL}=0.4V$	0.52		0.44	0.88	_	0.36	-	m A	
	IoL	10	$V_{OL}=0.5V$	1.3	_	1.1	2.25	_	0.9			
		15	$V_{OL} = 1.5 \text{V}$	3.6	_	3.0	8.8	_	2.4	_		
Input Current	Iin	15	· · · · · · · · · · · · · · · · · · ·	_	±0.3	_	±0.00001	±0.3	_	±1.0	μA	
Input Capacitance	Cin		$V_{in} = 0$	-	<u> </u>	_	5.0	7.5	_	_	pF	
Quiescent Current I		5.0	7 () 1		20	_	0.005	20	_	150	μA	
	I_{DD}	10	Zero Signal,	_	40	_	0.010	40		300		
		15	per Package	_	80	_	0.015	80	***	600		
Total Supply Current*		5.0	Dynamic $+I_{\scriptscriptstyle DD}$,	-	-	-	1.2		-	— ,	μΑ	
	I_T	10	$C_L = 50 \text{pF}, f = 1 \text{ kHz}$	_	_	_	2.4	_	_	_		
		15	per Gate	_	_		3.6	_	_	_		
Three-State Output Leakage Current	ITL	15		_	±1.0	_	±0.00001	±1.0	_	±7.5	μA	

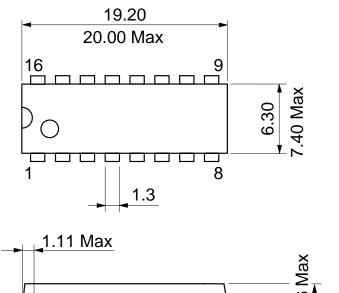
^{*} To calculate total supply current at frequency other than 1kHz.

■SWITCHING CHARACTERISTICS $(C_L=50 \text{pF}, Ta=25 ^{\circ}\text{C})$

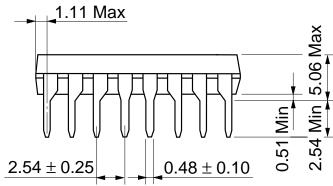
Characteristic	Symbol	$V_{DD}(\mathbf{V})$	min	typ	max	Unit	
Output Rise Time		5.0	_	180	400		
	t-	10		90	200	ns	
		15		65	160		
Output Fall Time	t f	5.0	_	100	200	ns	
		10	_	50	100		
		15	_	37	80		
Propagation Delay Time	tplн	5.0		250	500		
		10		115	225	ns	
		15		90	165		
	tpHL	5.0		250	500		
		10	_	115	225	ns	
		15		90	165		

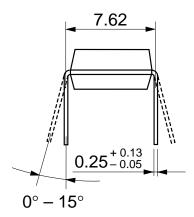
 $[@]V_{00} = 5.0V \\ I_{7} = (1.2\mu\text{A/kHz})f + I_{00} \\ @V_{00} = 10V \\ I_{7} = (2.4\mu\text{A/kHz})f + I_{00} \\ @V_{00} = 15V \\ I_{7} = (3.6\mu\text{A/kHz})f + I_{00} \\ @V_{00} = 15V \\ I_{7} = (3.6\mu\text{A/kHz})f + I_{00} \\ @V_{00} = 15V \\ O(10) = 15V \\ O($

Unit: mm









Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g

Cautions

- 1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as failsafes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica http:semiconductor.hitachi.com/ Europe

http://www.hitachi-eu.com/hel/ecg http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD_Frame.htm Asia (Singapore) Asia (Taiwan) Asia (HongKong) http://www.hitachi.com.hk/eng/bo/grp3/index.htm

http://www.hitachi.co.jp/Sicd/indx.htm Japan

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany

Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd. Flectronic Components Group Whitebrook Park Lower Cookham Road Maidenhead

Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100

Fax: 535-1533 Hitachi Asia Ltd.

Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281

Telex: 40815 HITEC HX

Copyright 'Hitachi, Ltd., 1999. All rights reserved. Printed in Japan.